



RF/Microwave Amplifier

Available as:

TM9547, 4 Pin 0.500" TO-8 Can (T4) TN9547, 4 Pin 0.450" Sq. Surface Mount (SM3) BX9547, SMA Connectorized Housing (H1L)



Features

• Low Noise Figure: 3.5 dB

No External Circuitry Needed

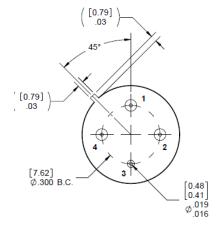
Unconditionally Stable

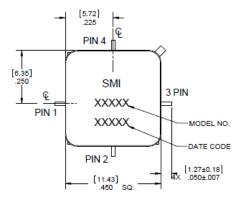
RoHS Design Compliant Option TM9547LF

Technical Specifications

Characteristic	TYPICAL Ta = +25 °C	MIN/MAX Ta = -55°C to +85 °C	
Frequency	10 – 3600 MHz	10 – 3500 MHz	
Gain (dB)	11	9.5 Min.	
Power @ 1 dB Comp. (dBm)	+20	+18 Min.	
Reverse Isolation (dB)	-30		
VSWR In	1.6:1	2.0:1 Max.	
Out	1.6:1	2.0:1 Max.	
Noise Figure (dB) (100-3500 MHz)	3.5	5.0 Max.	
Power Vdc	+15	+15	
mA	75	100 Max.	

- 1) Care should always be taken to effectively ground the case of each unit
- 2) Typical values are measured at 25°C, but not guaranteed.
- 3) Package drawings below are for reference only.





Typical Intermodulation Performance at 25 °C

Second Order Harmonic Intercept Point:	+54 dBm (Typ.)
Second Order Two Tone Intercept Point:	+48 dBm (Typ.)
Third Order Two Tone Intercept Point:	+33 dBm (Typ.)

Intercept Values Measured Midband

Absolute Maximum (No Damage) Ratings

Operating Temperature	-55°C to +100 °C
Storage Temperature	-62°C to +125°C
Case Temperature	+125 °C
DC Voltage	+18 Volts
Continuous RF Input Power	+23 dBm
Short Term RF Input Power	200 Milliwatts (1 Minute Max.)
Maximum Peak Power	0.5 Watt (3 µsec Max.)

Instructions

Grounding Instructions	Care should be taken to effectively ground each unit.	
Revisions	API reserves the right to make revisions to both product and/or the information contained within their datasheets without advanced notice.	
Min./Max. Values	Specifications are guaranteed when tested in a 50 Ω (ohm) system.	
Typical performance graphs and values are measured at 25°C, but not guaranteed.		

1) Outlines drawings below are for reference only.

